

## Researchers Unveil Unusual Bandgap Renormalization in 2D Inorganic Lead-Halide Perovskite Nanoplatelets



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Owing to high quantum yields, large absorption cross-section, excellent carrier transport performance and narrow-band emission, inorganic lead-halide perovskite semiconductors have received increasing attention for their applications in solar cells, LEDs, laser devices, etc. Understanding the physical origin of temperature dependence of bandgap in inorganic lead-halide perovskites is essential and important.

In a study published in [Adv. Sci.](#), the research group led by Prof. CHEN Xueyuan from Fujian Institute of Research on the Structure of Matter (FJIRSM) of the [Chinese Academy of Sciences](#) (CAS) found that the temperature dependence of bandgap in CsPbBr<sub>3</sub> perovskites is variable with material dimensionality.

The researchers conducted a comparative investigation on the temperature-dependent bandgap in quasi-3D bulk-like CsPbBr<sub>3</sub> nanocrystals (NCs) with weak quantum confinement and 2D 2-monolayer-thick CsPbBr<sub>3</sub> nanoplatelets (2-ML NPLs) featuring strong quantum confinement.

For the sake of more accurate determination of bandgap shift, the researchers elaborately extracted the bandgap energy through fitting the absorption coefficient near the band edge to the Elliot model. The extracted bandgap value of CsPbBr<sub>3</sub> 2-ML NPLs exhibited an initial blueshift and then a redshift trend with decreasing temperature from 290 to 10 K, in sharp contrast to the monotonous redshift usually observed in CsPbBr<sub>3</sub> bulk-like NCs.

From the theoretical point of view, the bandgap renormalization essentially arises from the lattice thermal expansion and electron-phonon interactions. However, for a large variety of semiconductor materials and in particular the lead-based compounds, the thermal expansion contribution to bandgap renormalization was not taken into account because it had a

relatively small magnitude with respect to the contribution from electron-phonon interactions.

Owing to the breaking translational periodicity in the thickness direction of 2D CsPbBr<sub>3</sub> 2-ML NPLs, the electron and phonon structures, and consequently the bandgap renormalization deriving from electron-phonon interactions are apt to change remarkably relative to the quasi-3D CsPbBr<sub>3</sub> NCs counterparts. The strong quantum confinement effect and the reduced dielectric screening due to the low dielectric constant of surface organic ligands in CsPbBr<sub>3</sub> 2-ML NPLs also influence the electron-phonon interactions.

The researchers adopted the Bose-Einstein two-oscillator model to determine the effective electron-phonon interaction coefficient through fitting the bandgap as a function of temperature. The results manifested significantly larger weight of contribution from electron-optical phonon interaction to bandgap renormalization in the NPLs than that in the NCs accounts for the blueshift-redshift crossover of bandgap in NPLs.

This study provides new insights into the pivotal role of electron-phonon interactions in the bandgap renormalization for 2D inorganic lead-halide perovskites, which may pave the way for further investigations on the optical and optoelectronic properties of 2D perovskite nanomaterials.

Read the [original article](#) on Chinese Academy of Sciences.